NSN 5962-01-500-3836

Memory Microcircuit - Page 1 of 1



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1.2 watts Operating Tempurature Range: -55.0/+125.0 degrees celsius Storage Tempurature Range: -65.0/+150.0 degrees celsius Features Provided: Electrostatic sensitive and monolithic and bipolar Inclosure Material: Ceramic
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Features Provided: Electrostatic sensitive and monolithic and bipolar Inclosure Material:
Electrostatic sensitive and monolithic and bipolar Inclosure Material:
Inclosure Material:
Ceramic
Inclosure Configuration:
Leadless flat pack
Product Name:
Microcircuit, digital, memory, bipolar, programming logic, monolithic silicon
Voltage Rating And Type Per Characteristic:
-0.5 volts input and 7.0 volts input
Memory Device Type:
Pal
Special Features:
Generic p/n pal20r6-10
Test Data Document:
96906-mil-std-883 standard (includes industry or association standards, individual manufactureer standards, etc.)
Terminal Type And Quantity:
28 leadless
Shelf Life:
N/a
Unit Of Measure:
Demilitarization:
Yes - demil/mli
Fiig:
A458a0